

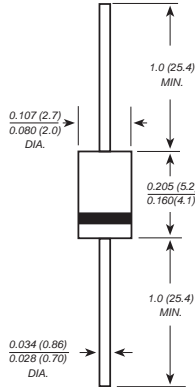


SB120 THRU SB1200

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 1.0 Ampere

DO-41



Dimensions in inches and (millimeters)

FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
250°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC DO-41 molded plastic body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.012 ounce, 0.33 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SB 120	SB 130	SB 140	SB 150	SB 160	SB 170	SB 180	SB 190	SB 1B0	SB 1150	SB 1200	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	70	80	90	100	150	200	VOLTS
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	49	56	63	70	105	140	VOLTS
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	70	80	90	100	150	200	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length (see fig.1)	$I_{(AV)}$	1.0											Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	40.0											Amps
Maximum instantaneous forward voltage at 1.0A	V_F	0.55		0.70		0.85				0.95		Volts	
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	0.5								0.2		mA	
		10.0				5.0				2.0			
Typical junction capacitance (NOTE 1)	C_J	110				80				pF			
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0											°C/W
Operating junction temperature range	T_J	-65 to +125				-65 to +150				°C			
Storage temperature range	T_{STG}	-65 to +150											°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

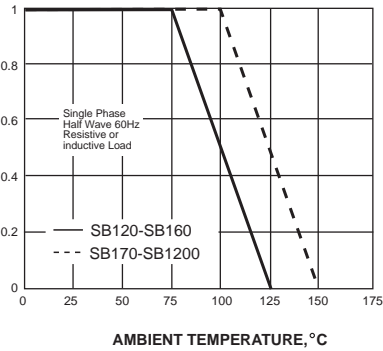
2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

MDD ELECTRONIC

RATINGS AND CHARACTERISTIC CURVES SB120 THRU SB1200

AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

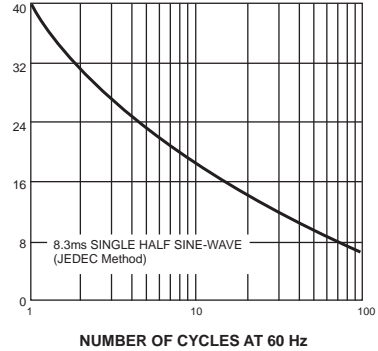


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

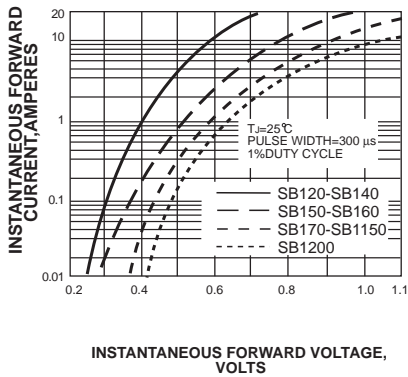


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

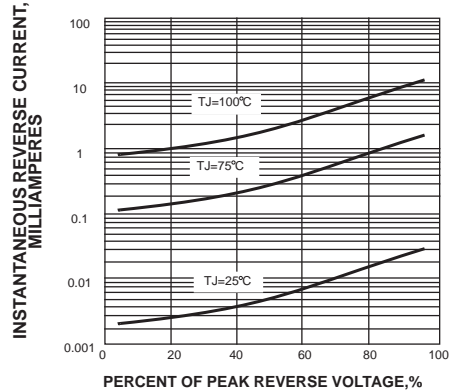


FIG. 5-TYPICAL JUNCTION CAPACITANCE

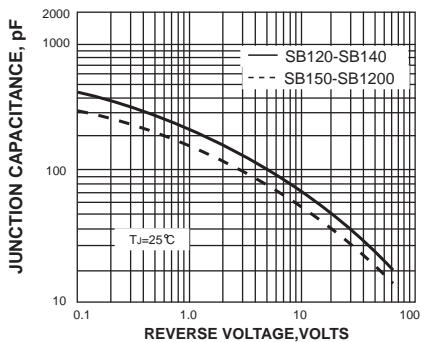


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

